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THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICATION OF:

Adolf Bernds et al.

SERIAL NO:

10/542,679

GROUP ART UNIT:

Not assigned

FILED:

July 19, 2005

EXAMINER:

Not assigned

CUSTOMER NO.:

27162

FOR:

Use of Conductive Black/Graphite Mixtures For The Production

of Low-Cost Electronics

ATTY/DKT NO.:

411000-141

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

SIR:

Pursuant to 37 C.F.R. §1.56(a), Applicant(s) hereby cite(s) the enclosed documents listed on the attached copy of Form PTO-1449 which are believed to be material to the patentability of the above-identified application.

This Information Disclosure Statement is filed in accordance with the paragraph of 37 CFR §1.97 indicated below:

X §1.97(b)

This Information Disclosure Statement is filed:

- (1) Within three months of the filing date of a national application; OR
- (2) Within three months of the date of entry of the national stage of an international application; OR
- (3) Before the mailing of a first Office Action on the merits. No fee or statement is required.

____§1.97(c) This Information Disclosure Statement is filed after the period specified in paragraph (b) above, but before the mailing date of either:

- (1) A Final Action or under 37 CFR §1.113; OR
- (2) A Notice of Allowance under 37 CFR §1.311; AND

K

is accompanied by either: (check one)

		he statement as specified in 37 CFR §1.97(e) set out below; OR
	Т	he fee of \$180.00 under 37 CFR §1.17(p).
§1.97(d)	This Information	n Disclosure Statement is filed after the mailing date
		Final Action or under 37 CFR §1.113; OR
	` '	Notice of Allowance under 37 CFR §1.311;
		before payment of the Issue Fee; AND
		npanied by:
		he statement as specified in 37 CFR §1.97(e) as set orth below; AND
	C	etition is hereby made under 37 CFR §1.97(d) for onsideration of this Information Disclosure Statement; ND,
	(3) T	he petition fee of \$180.00 set out in 37 CFR §1.17(i).
§1.97(e)	The undersigne	ed Attorney hereby states that:
	Statement was office in a coun prior to the filing	nformation contained in this Information Disclosure first cited in any communication from a foreign patent terpart foreign application not more than three months date of this Information Disclosure Statement;
	Statement was in a counterpa undersigned At any individual	formation contained in this Information Disclosure cited in a communication from a foreign patent office art foreign application, or to the knowledge of the torney after making reasonable inquiry, was known to designated in 37 CFR §1.56(c) more than three to the filing date of the Information Disclosure

The relevancy of the cited patents, the foreign language and other documents listed on the attached PTO 1449 is that these documents were cited in the copending applications noted in the accompanying Disclosure Statement or were cited in a foreign application that may have subject matter generally related to the subject matter of one or more of the cited copending applications.

The Commissioner is authorized to charge payment of any fees associated with this communication or credit any overpayment to Deposit Account No. 03-0678.

FIRST CLASS CERTIFICATE

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P.O. Box 1450

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Sept. 27, 2005

jánice Spéidel **Date**

#270240

Respectfully submitted,

Adolf Bernds et al.

William Squire Reg. No. 25,378 CARELLA, BYRNE,BAIN, GILFILLAN,

CECCHI, STEWART & OLSTEIN

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Tel: (973)994-1700

Fax: (973)994-1744

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICATION

Adolf Bemds et al.

OF:

SERIAL NO:

10/542,679

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DISCLOSURE STATEMENT UNDER 37 CFR 1.56

SIR:

This paper is to bring to the attention of the PTO the following commonly owned copending U.S. applications, all of which are related in different respects to organic electronic devices and/or method of making such devices such as transistors, diodes, integrated circuits and the like. Many of these applications also have one or more common inventors. The enclosed PTO 1449 lists these applications. It is respectfully requested that the Examiner consider and make of record all of the cited applications listed on the attached PTO 1449.

Application No.	<u>Title</u>	<u>Inventors</u>	Atty. Dkt. No.
10/332,140	Method for the Production and Configuration of Organic Field-Effect Transistors (OFET)	Adolf Bernds et al.	411000-103

10/344,951	Organic Field-Effect Transistor (OFET), A Production Method Therefor, An Integrated Circuit Constructed From the Same and Their Uses	Adolf Bernds et al.	411000-99
10/362,932	Organic Field Effect Transistor, Method for Structuring an OFET and Integrated Circuit	Adolf Bernds et al	411000-110
10/380,113	Organic Rectifier, Circuit, RFID Tag and Use of an Organic Rectifier	Adolf Bernds et al.	411000-106
10/380,206	Organic Memory, Identification Marker (RFID-TAG) with Organic Memory and Uses of an Organic Memory	Adolf Bernds et al.	411000-102
10/381,032	Electrode and/or Conductor Track for Organic Components and Production Method Thereof	Adolf Bernds et al.	411000-105
10/433,959	Organic Field Effect Transistor, Method For Structuring an OFET and Integrated Circuit	Adolf Bernds	411000-108
10/433,961	Device For Detecting and/or Transmitting at Least One Environmental Influence, Method for Producing Said Device and Use Thereof	Wolfgang Clemens et al.	411000-111
10/467,636	Organic Field Effect Transistor With a Photostructured Gate Dielectric, Method for the Production and Use Thereof in Organic Electronics	Adolf Bernds et al.	411000-104
10/473,050	Device With At Least Two Organic Electronic Components and Method for Producing the Same	Adolf Bernds et al.	411000-113
10/479,234	Organic Field Effect Transistor, Method for Production and Use Thereof in the Assembly of Integrated Circuits	Adolf Bernds et al.	411000-101
10/479,238	Method For Producing Conductive Structures by Means of Printing Technique, and Active Components Produced Therefrom For Integrated Circuits	Adolf Bernds et al.	411000-100
10/492,922	Insulator for An Organic Electronic Component	Erwann Guillet et al.	411000-115
10/492,923	Electronic Unit, Circuit Design for the Same and Production Method	Wolfgang Clemens et al.	411000-114
10/498,610	Organic Field Effect Transistor with Offset Threshold Voltage and the Use Thereof	Walter Fix et al.	411000-119
10/508,640	Logic Component Comprising Organic Field Effect Transistors	Walter Fix et al.	411000-120

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10/508,737	Device and Method for Laser Structuring Functional Polymers and	Adolf Bernds et al.	411000-121
10/517,750	Substrate for an Organic Field Effect Transistor, Use of the Substrate, Method of Increasing the Charge Carrier Mobility and Organic Field Effect Transistor (OFET)	Wolfgang Clemens et al.	411000-122
10/523,216	Electronic Component Comprising Predominantly Organic Functional Materials And A Process For The Production Thereof	Adolf Bernds et al.	411000-123
10/523,487	Electronic Device	Wolfgang Clemens et al.	411000-124
10/524,646	Organic Component for Overvoltage Protection and Associated Circuit	Walter Fix et al.	411000-127
10/533,756	Organic Electronic Component with High- Resolution Structuring and Process for the Production Thereof	Wolfgang Clemens et al.	411000-128
10/534,678	Measuring Apparatus for Determining an Analyte in a Liquid Sample	Wolfgang Clemens et	411000-129
10/535,448	Organic Electronic Component Comprising Semi-Conductive Functional Layer and Method for Producing Said Component	Wolfgang Clemens et al.	411000-131
10/535,449	Organic Electronic Component Comprising the Same Organic Material for at Least Two Functional Layers	Adolf Bernds et al.	411000-132
10/344,926	An Electronic Circuit Having an Encapsulated Organic-Electronic Component, and a Method for Making an Encapsulated Organic-Electronic Component	Wolfgang Clemens et al.	411000-133
10/541,815	Organo-Resistive Memory Unit	Axel Gerlt et al.	411000-136
10/541,956	Board or Substrate for an Organic Electronic Device and Use Thereof	Wolfgang Clemens et al.	411000-137
10/541,957	Organic Field Effect Transistor And Integrated Circuit	Walter Fix et al.	411000-138
10/543,561	Organic Storage Component and Corresponding Triggering Circuit	Wolfgang Clemens et al.	411000-139
10/542,678	Organic Electronic Component and Method For Producing Organic Electronic Devices	Adolf Bernds et al.	411000-140
10/542,679	Use of Conductive Carbon Black/Graphite Mixtures for the Production of Low-Cost Electronics	Adolf Bernds et al.	411000-141

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Janice Speidel

Sept. 27, 2005

Date

#270243

Respectfully submitted, Adolf Bernds et al.

William Squire Reg. No. 25,378

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_	Under the Paperwork Re	duction Act of 1995, no persons are re	U.S. Patent and Tra	PTO/SB/08a (08-03) d for use through 07/31/2006. OMB 0651-0031 ademark Office; U.S. Department of Commerce n unless it displays a valid OMB control number	
Substitute fo	substitute for form 1449A/PTO Complete if Known				
			Application Number	10/542,679	
	INFORMATION DIS	CLOSURE	Filing Date	July 19, 2005	
	STATEMENT BY A	PPLICANT	First Named Inventor	Adolf Bernds	
			Group Art Unit	Not assigned	
	(Use as many sheets as	necessary)	Examiner Name	Not assigned	
Sheet	1	2	Attorney Docket Number	411000-141	

			U.S. PATENT DOC	JMENTS	
Examiner Initial*	Cite No.1	Document Number Number-Kid Code ^{2 (f known)}	Publication- Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
	103	US-6,852,583	10/09/2003	Adolf Bernds et al.	See accompanying Disclosure Statement filed herewith
	102	US-6,903,958	03/21/2002	Adolf Bernds et al.	
	133	US-10/344,926	02/12/2004	Adolf Bernds et al.	
	99	US-10/344,951	02/12/2004	Adolf Bernds et al.	
	110	US-10./362,932	10/02/2003	Adolf Bernds et al.	
	106	US-10/380,113	09/25/2003	Adolf Bernds et al.	
	105	US-10/381,032	02/12/2004	Adolf Bernds et al.	
	108	US-10/433,959	04/01/2004	Adolf Bernds	
	111	US-10/433,961	04/01/2004	Wolfgang Clemens et al.	
	109	US-10/451,108	05/13/2004	Mark Giles et al.	
	104	US-10/467,636	11/04/2004	Adolf Bernds et al.	
	113	US-10/473,050	05/20/2004	Adolf Bernds et al.	
	101	US-10/479,234	12/30/2004	Adolf Bernds et al.	
	100	US-10/479,238	10/20/2004	Adolf Bernds et al.	
	115	US-10/492,922	03/03/2005	Erwann Buillet et al.	
	114	US-10/492,923	12/23/2004	Wolfgang Clemens et al.	
	119	US-10/498,610	N/A	Walter Fix et al.	
	120	US-10/508,640	N/A	Walter Fix et al.	
	121	US-10/508,737	N/A	Adolf Bernds et al.	
	122	US-10/517,750	N/A	Wolfgang Clemens et al.	
	123	US-10/523,216	N/A	Adolf Bernds et al.	
	124	US-10/523,487	N/A	Wolfgang Clemens et al.	
	127	US-10/524,646	N/A	Walter Fix et al.	
	128	US-10/533,756	N/A	Wolfgang Clemens et al.	

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Substitute f	or form 1449A/PTO		Com	plete if Known
			Application Number	10/542,679
	INFORMATION DISC	LOSURE	Filing Date	July 19, 2005
	STATEMENT BY APP	LICANT	First Named Inventor	Adolf Bernds
			Group Art Unit	Not assigned
	(Use as many sheets as ne	cessary)	Examiner Name	Not assigned
Sheet	2	2	Attorney Docket Number	411000-141

	129	US-10/534,678	N/A	Wolfgang Clemens et al.	
	131	10/535,448	N/A	W. Clemens et al.	
	132	10/535,449	N/A	Walter Fix et al.	
	136	US-10/541,815	N/A	Axel Gerit et al.	
	137	US-10/541,956	N/A	Wolfgang Clemens et al.	
	138	US10/541,957	N/A	Walter Fix et al.	
	139	US-10/543,561	N/A	Wolfgang Clemens et al.	
	140	US-10/542,678	N/A	Adolf Bernds et al.	
,	141	US-10/542,679	N/A	Adolf Bernds et al.	
xaminer	r Signature			Date Considered	

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. 1 Applicant's unique citation designation number (optional). 2 See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. 3 Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). 4 For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. 5 Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. 8 Applicant is to place a check mark here if English language Translation is attached. This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

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Substitute	for form 1449A/PTO	• Complete if Known			lete if Known
				Application Number	10/542,679
	INFORMATION DISC	LOSUF	RE	Filing Date	July 19, 2005
	STATEMENT BY API	PLICAN	NT	First Named Inventor	Adolf Bernds
				Group Art Unit	Not assigned
	(Use as many sheets as n	ecessary)	Examiner Name	Not assigned
Sheet	1	Of	11	Attomey Docket Number	411000-141

			U.S. PATENT DOCL	IMENTS	
Examiner Initial*	Cite No. ¹	Document Number Number-Kid Code ^{2 (if known)}	Publication- Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages o Relevant Figures Appear
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		US-2002/0056839	05-16-2002	Joo et al.	
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		US-2002/0018911	02-00-2002	Bernius et al.	
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		US-2002/025391	02-28-2002	Angelopoulos	
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		US-2003/0112576	06-19-2003	Brewer et al.	
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Substitute for form 1449A/PTO Complete if Known 10/542,679 Application Number **INFORMATION DISCLOSURE** Filing Date July 19, 2005 **STATEMENT BY APPLICANT** First Named Inventor Adolf Bernds Not assigned Group Art Unit

	(Use as many sheets as n	ecessary)	Examiner Name	Not assigned
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Sheet

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use as many sheets as necessary)

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Complete if Known					
Application Number	10/542,679				
Filing Date	July 19, 2005				
First Named Inventor	Adolf Bernds				
Group Art Unit	Not assigned				
Examiner Name	Not assigned				
Attorney Docket Number	411000-141				

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US-6,903,958	06-07-2005	Bernds et al.	

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Examiner	Cite	Foreign Patent Document	Publication- Date	Name of Patentee or	Pages, Columns, Lines,	
Initial*	No. ¹	Country Code ³ Number ⁴ Kind Code ⁵ (if known)	MM-DD-YYYY	Applicant of Cited Document	Where Relevant Passages or Relevant Figures Appear	Т6
		DE 100 06 257	09-14-2000	IBM		
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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use as many sheets as necessary)

Sheet 4 11

Complete if Known				
Application Number	10/542,679			
Filing Date	July 19, 2005			
First Named Inventor	Adolf Bernds			
Group Art Unit	Not assigned			
Examiner Name	Not assigned			
Attorney Docket Number	411000-141			

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GB 2 058 462	04-08-1981	Shin-Etsu Polymer Co.	Х

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use as many sheets as necessary)

Sheet 5 11

Complete if Known				
Application Number 10/542,679				
Filing Date	July 19, 2005			
First Named Inventor	Adolf Bernds			
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